1. General description

100 mA PNP Resistor-Equipped Transistor (RET) family in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

Table 1. Product overview

Type number	R1	R2		Package	NPN complement:
	kΩ	kΩ	Nexperia	JEDEC	
PDTA143EQB	4.7	4.7	SOT8015	MO-340BA	PDTC143EQB
PDTA114EQB	10	10			PDTC114EQB
PDTA124EQB	22	22			PDTC124EQB
PDTA144EQB	47	47			PDTC144EQB

2. Features and benefits

- · 100 mA output current capability
- Built-in resistors
- · Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- Suitable for Automatic Optical Inspection (AOI) of solder joint

3. Applications

- Digital applications
- Cost saving alternative for BC857 series in digital applications
- · Controlling IC inputs
- Switching loads

4. Quick reference data

Table 2. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA



5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)		
2	GND	GND (emitter)	3	R1
3	0	output (collector)		
			1 2	GND
			Transparent top view	aaa-019000

6. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
PDTA143EQB		plastic leadless extremely thin small outline package with	SOT8015				
PDTA114EQB		side-wettable flanks (SWF); 3 terminals; 0.65 mm pitch; body: 1.1 x 1.0 x 0.48 mm					
PDTA124EQB		body. 1.1 × 1.0 × 0.40 mm					
PDTA144EQB							

7. Marking

Table 5. Marking

Type number	Marking code
PDTA143EQB	D5
PDTA114EQB	C8
PDTA124EQB	D3
PDTA144EQB	D8

8. Limiting values

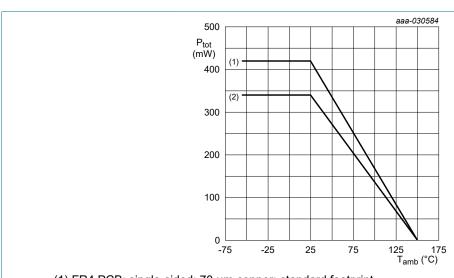
Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit				
V _{CBO}	collector-base voltage	open emitter		-	-50	V				
V _{CEO}	collector-emitter voltage	open base		-	-50	V				
V _{EBO}	emitter-base voltage	open collector		-	-10	V				
V _I	input voltage	input voltage								
	PDTA143EQB			-30	+10	V				
	PDTA114EQB			-40	+10	V				
	PDTA124EQB			-40	+10	V				
	PDTA144EQB			-40	+10	V				
lo	output current			-	-100	mA				
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	340	mW				
			[2]	-	420	mW				
Tj	junction temperature			-	150	°C				
T _{amb}	ambient temperature			-55	150	°C				
T _{stg}	storage temperature			-65	150	°C				

- [1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided; 35 µm copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.



- (1) FR4 PCB; single-sided; 70 µm copper; standard footprint
- (2) FR4 PCB; single-sided; 35 µm copper; standard footprint

Fig. 1. Power derating curves

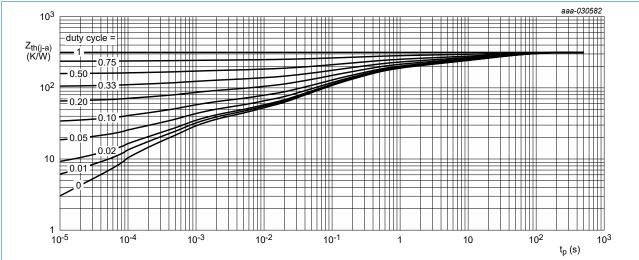
9. Thermal characteristics

Table 7. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

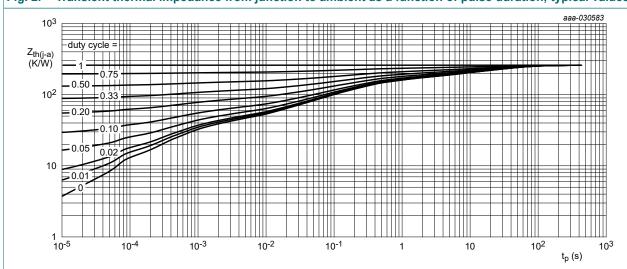
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	368	K/W
			[2]	-	-	298	K/W

- [1] Device mounted on an FR4 PCB; single-sided; 35 µm copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70 μm copper; tin-plated and standard footprint.



FR4 PCB; single-sided; 35 µm copper; tin-plated and standard footprint.

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided; 70 µm copper; tin-plated and standard footprint.

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

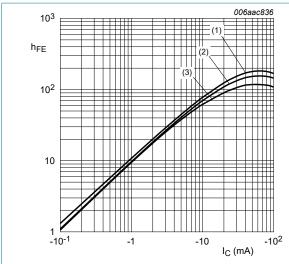
Table 8. Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
V _{(BR)CBO}	collector-base breakdown voltage	I _C = -100 μA; I _E = 0 A		-50	-	-	V		
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = -2 mA; I _B = 0 A		-50	-	-	V		
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$		-	-	-100	nA		
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A		-	-	-100	nA		
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μA		
I _{EBO}	emitter-base cut-off curr	ent							
	PDTA143EQB	V _{EB} = -5 V; I _C = 0 A		-	-	-900	μΑ		
	PDTA114EQB			-	-	-400	μΑ		
	PDTA124EQB			-	-	-180	μA		
	PDTA144EQB					-90	μA		
h _{FE}	DC current gain								
PD'	PDTA143EQB	V _{CE} = -5 V; I _C = -10 mA		30	-	-	T		
	PDTA114EQB	$V_{CE} = -5 \text{ V; } I_{C} = -5 \text{ mA}$		30	-	-			
	PDTA124EQB			60	-	-			
	PDTA144EQB			80	-	-			
V _{CEsat}	collector-emitter saturation voltage	I _C = -10 mA; I _B = -0.5 mA		-	-	-100	mV		
V _{I(off)}	off-state input voltage								
	PDTA143EQB	V _{CE} = -5 V ; I _C = -100 μA		-	-1.1	-0.5	V		
	PDTA114EQB			-	-1.1	-0.8	V		
	PDTA124EQB			-	-1.1	-0.8	٧		
	PDTA144EQB			-	-1.2	-0.8	V		
V _{I(on)}	on-state input voltage		-	1			_		
	PDTA143EQB	V _{CE} = -0.3 V ; I _C = -20 mA		-2.5	-1.9	-	V		
	PDTA114EQB	V _{CE} = -0.3 V ; I _C = -10 mA		-2.5	-1.8	-	V		
	PDTA124EQB	$V_{CE} = -0.3 \text{ V}$; $I_{C} = -5 \text{ mA}$		-2.5	-1.7	-	V		
	PDTA144EQB	$V_{CE} = -0.3 \text{ V}$; $I_{C} = -2 \text{ mA}$		-3.0	-1.6	-	V		
R1	bias resistor 1 (input)		<u>'</u>	'					
	PDTA143EQB		[1]	3.3	4.7	6.1	kΩ		
	PDTA114EQB	-		7	10	13	kΩ		
	PDTA124EQB			15.4	22	28.6	kΩ		
	PDTA144EQB			33	47	61	kΩ		
R2/R1	bias resistor ratio			8.0	1	1.2			
f _T	transition frequency	V _{CE} = -5 V; I _C = -10 mA; f = 100 MHz	[2]	-	180	-	MHz		
C _c	collector capacitance	V _{CB} = -10 V; I _E = i _e = 0 A; f = 1 MHz		-	-	3	pF		

^[1] See "Section 11: Test information" for resistor calculation and test conditions

^[2] Characteristics of built-in transistor



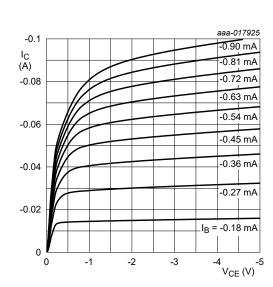
 $V_{CE} = -5 V$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

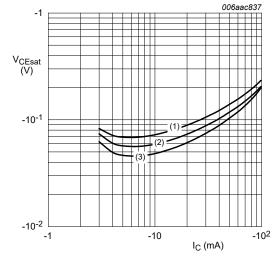
(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 4. PDTA143EQB: DC current gain as a function of collector current; typical values



 T_{amb} = 25 °C

Fig. 5. PDTA143EQB: Collector current as a function of collector-emitter voltage; typical values



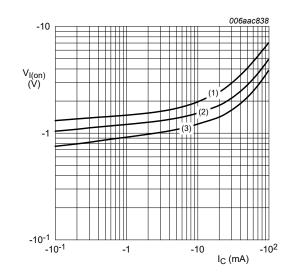
 $I_{\rm C}/I_{\rm B} = 20$

$$(1) T_{amb} = 100 °C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 6. PDTA143EQB: Collector-emitter saturation voltage as a function of collector current; typical values



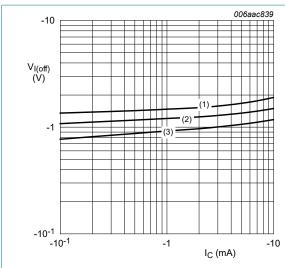
 V_{CE} = -0.3 V

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. PDTA143EQB: On-state input voltage as a function of collector current; typical values



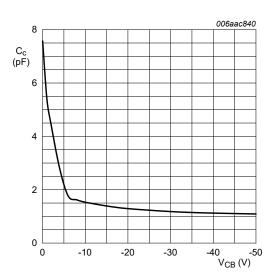
$$V_{CE} = -5 V$$

(1)
$$T_{amb}$$
 = -40 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 100 °C

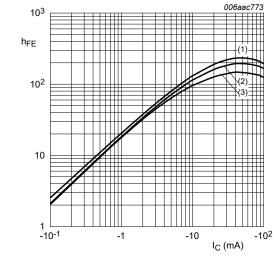
PDTA143EQB: Off-state input voltage as a Fig. 8. function of collector current; typical values



f = 1 MHz

$$T_{amb}$$
 = 25 °C

PDTA143EQB: Collector capacitance as a Fig. 9. function of collector-base voltage; typical values



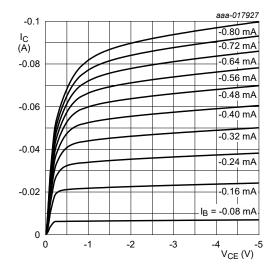
 $V_{CE} = -5 V$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

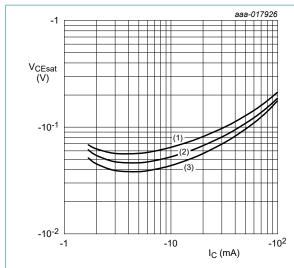
(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 10. PDTA114EQB: DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig. 11. PDTA114EQB: Collector current as a function of collector-emitter voltage; typical values

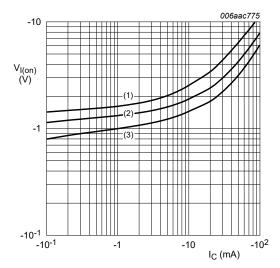


$$I_{\rm C}/I_{\rm B} = 20$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 12. PDTA114EQB: Collector-emitter saturation voltage as a function of collector current; typical values



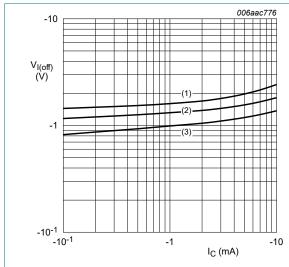
$$V_{CE}$$
 = -0.3 V

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 13. PDTA114EQB: On-state input voltage as a function of collector current; typical values



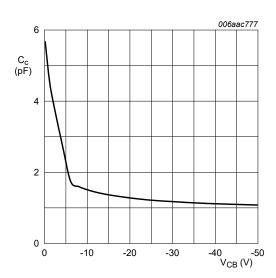
$$V_{CE}$$
 = -5 V

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

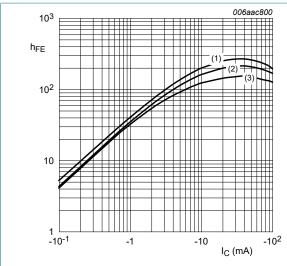
(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 14. PDTA114EQB: Off-state input voltage as a function of collector current; typical values



f = 1 MHz

Fig. 15. PDTA114EQB: Collector capacitance as a function of collector-base voltage; typical values



$$V_{CE} = -5 V$$

(1)
$$T_{amb}$$
 = 100 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 16. PDTA124EQB: DC current gain as a function of collector current; typical values

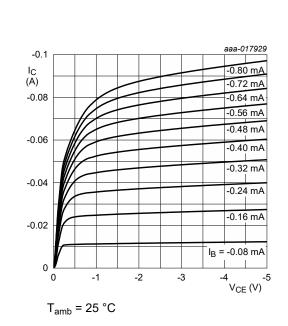
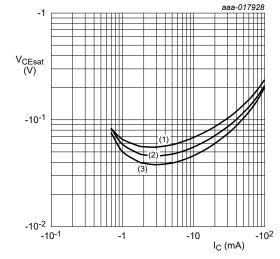


Fig. 17. PDTA124EQB: Collector current as a function of collector-emitter voltage; typical values



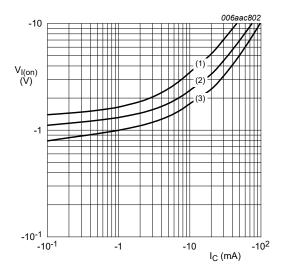
$$I_C/I_B = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 18. PDTA124EQB: Collector-emitter saturation voltage as a function of collector current; typical values



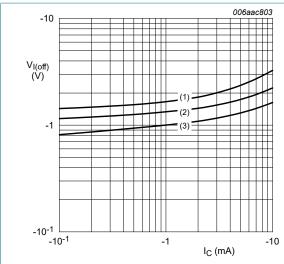
$$V_{CE} = -0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 19. PDTA124EQB: On-state input voltage as a function of collector current; typical values



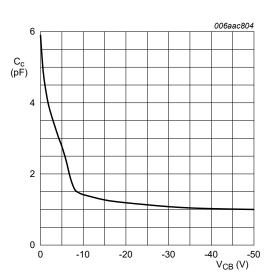
$$V_{CE} = -5 V$$

(1)
$$T_{amb}$$
 = -40 °C

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb}$$
 = 100 °C

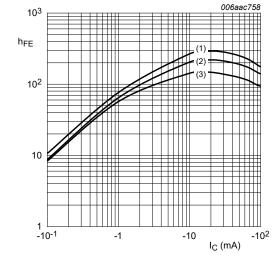
Fig. 20. PDTA124EQB: Off-state input voltage as a function of collector current; typical values



f = 1 MHz

$$T_{amb}$$
 = 25 °C

Fig. 21. PDTA124EQB: Collector capacitance as a function of collector-base voltage; typical values



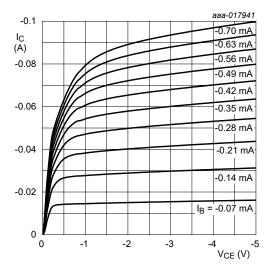
 $V_{CE} = -5 V$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

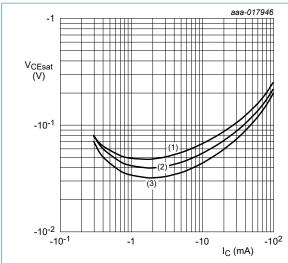
(3) $T_{amb} = -40 \, ^{\circ}C$

Fig. 22. PDTA144EQB: DC current gain as a function of collector current; typical values



T_{amb} = 25 °C

Fig. 23. PDTA144EQB: Collector current as a function of collector-emitter voltage; typical values

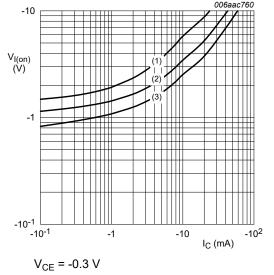


$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb}$$
 = 100 °C

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 24. PDTA144EQB: Collector-emitter saturation voltage as a function of collector current; typical values

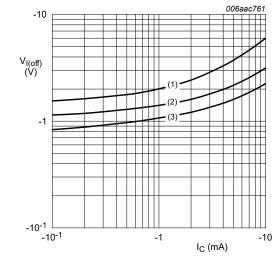


(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 25. PDTA144EQB: On-state input voltage as a function of collector current; typical values



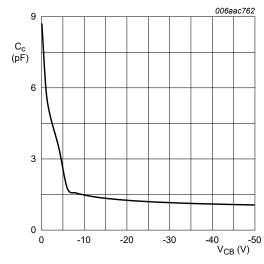
$$V_{CE} = -5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

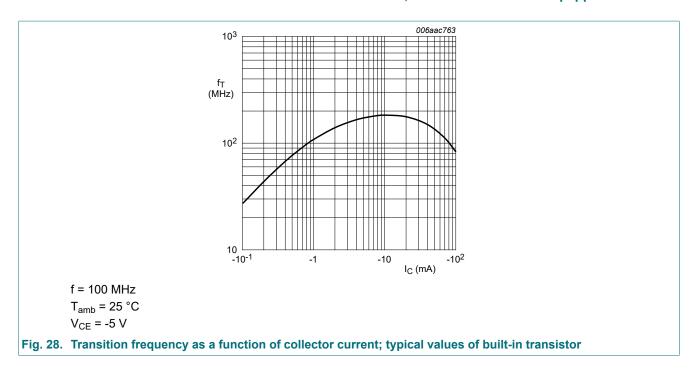
(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 26. PDTA144EQB: Off-state input voltage as a function of collector current; typical values



f = 1 MHz

Fig. 27. PDTA144EQB: Collector capacitance as a function of collector-base voltage; typical values of built-in transistor



11. Test information

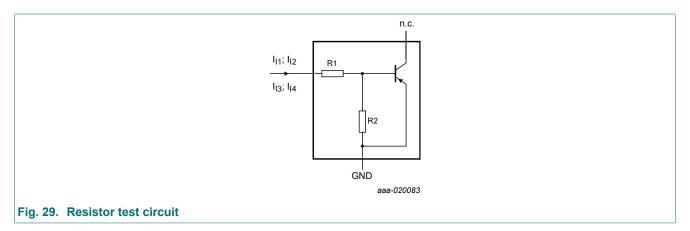
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

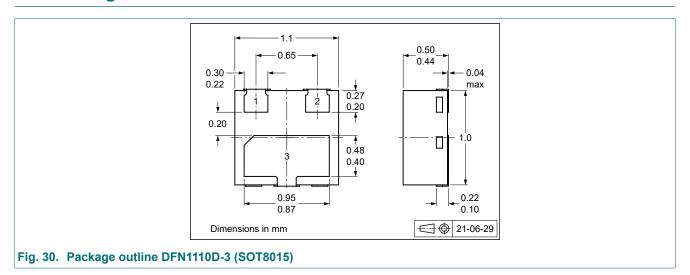


Resistor test conditions

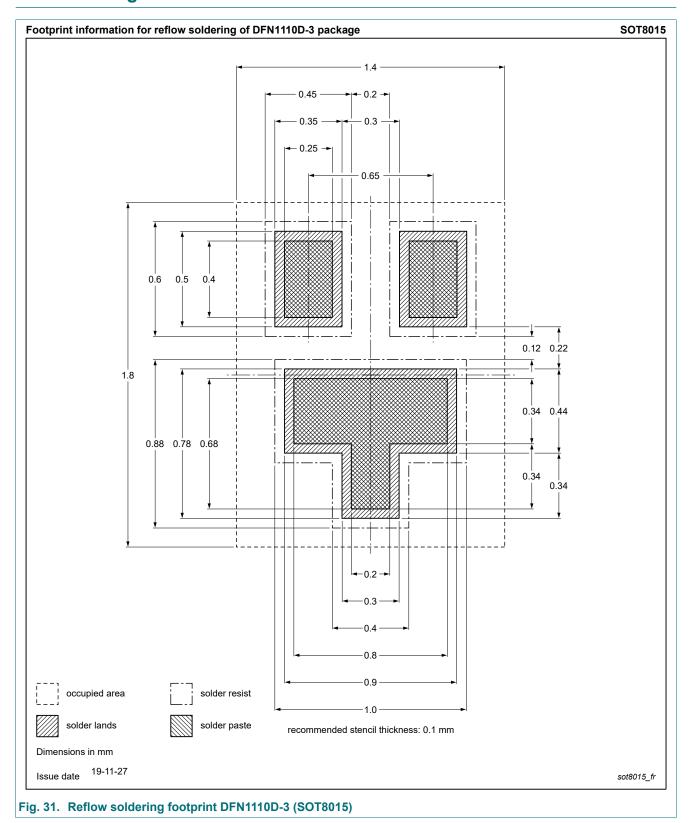
Table 9. Resistor test conditions

				Tuble of Redictor took contactions								
R1 (kΩ)	R2 (kΩ)	Test conditi	Test conditions									
		I _{I1}	I _{I2}	I _{I3}	I ₁₄							
4.7	4.7	-600 µA	-700 μA	600 µA	700 μA							
10	10	-350 µA	-450 μA	350 μΑ	450 µA							
22	22	-150 μA	-230 μA	150 µA	230 μΑ							
47	47	-55 μA	-105 μA	55 µA	105 μΑ							
	4.7 10 22	4.7 4.7 10 10 22 22	I _{I1} 4.7 4.7 10 10 -350 μA 22 22 -150 μA	I ₁₁ I ₁₂ 4.7 -600 μA -700 μA 10 10 -350 μA -450 μA 22 22 -150 μA -230 μA	I ₁₁ I ₁₂ I ₁₃ 4.7 -600 μA -700 μA 600 μA 10 10 -350 μA -450 μA 350 μA 22 22 -150 μA -230 μA 150 μA							

12. Package outline



13. Soldering



14. Revision history

Table 10. Revision history

Data sheet ID	Release date		Change notice	Supersedes
PDTA143_114_124_144EQB_SER v.1	20210928	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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Product data sheet

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For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 28 September 2021

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